SCAS009B - D2957, JULY 1987 - REVISED APRIL 1993

- Compares Two 8-Bit Words
- Inputs Are TTL-Voltage Compatible
- Flow-Through Architecture Optimizes
  PCB Layout
- Center-Pin V<sub>CC</sub> and GND Configurations Minimize High-Speed Switching Noise
- EPIC™ (Enhanced-Performance Implanted CMOS) 1-μm Process
- 500-mA Typical Latch-Up Immunity at 125°C
- The Device Has the Equivalent of 20-kΩ
  Pullup Resistors on Q Inputs
- Package Options Include Plastic Small- Outline Packages, Ceramic Chip Carriers, and Standard Plastic and Ceramic 300-mil DIPs

### description

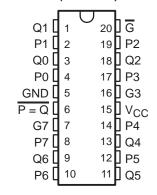
These identity comparators perform comparisons on two 8-bit binary or BCD words. Features include 20-k $\Omega$  pullup termination resistors on the Q inputs for analog or switch data and a  $\overline{P} = \overline{Q}$  totem-pole output.

The 54ACT11520 is characterized for operation over the full military temperature range of  $-55^{\circ}$ C to 125°C. The 74ACT11520 is characterized for operation from  $-40^{\circ}$ C to  $85^{\circ}$ C.

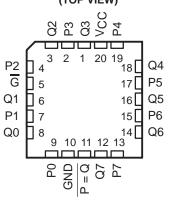
#### **FUNCTION TABLE**

INF	OUTPUT				
DATA P, Q	ENABLE G	P = Q			
P = Q	L	L			
P > Q	L	Н			
P < Q	L	Н			
Х	Н	Н			

#### 54ACT11520 . . . J PACKAGE 74ACT11520 . . . DW OR N PACKAGE (TOP VIEW)

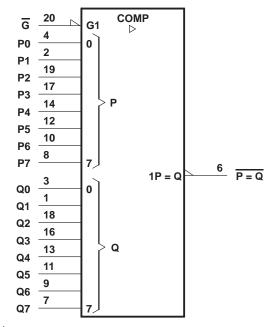


# 54ACT11520 . . . FK PACKAGE (TOP VIEW)



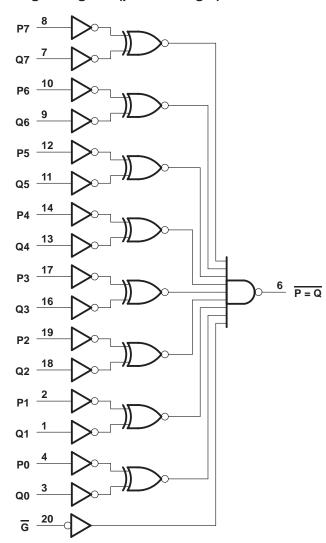
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### logic symbol†



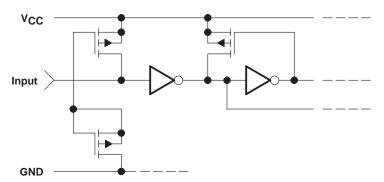
<sup>†</sup> This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

### logic diagram (positive logic)



Pin numbers shown are for the DW, J, and N packages.

## schematic of Q inputs



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## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V <sub>CC</sub>	0.5 V to 7 V
Input voltage range, V <sub>I</sub> (see Note 1)	$\dots$ -0.5 V to V <sub>CC</sub> + 0.5 V
Output voltage range, V <sub>O</sub> (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Input clamp current, $I_{IK}$ ( $V_I < 0$ or $V_I > V_{CC}$ )	± 20 mA
Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0 or V <sub>O</sub> > V <sub>CC</sub> )	$\dots \dots \pm 50 \text{ mA}$
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$	$\dots \dots \pm 50 \text{ mA}$
Continuous current through V <sub>CC</sub> or GND	±100 mA
Storage temperature range	

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

### recommended operating conditions

		54	54ACT11520		74ACT11520			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	UNII
Vcc	Supply voltage	4.5	5	5.5	4.5	5	5.5	V
VIH	High-level input voltage	2			2			V
V <sub>IL</sub>	Low-level input voltage			0.8			0.8	V
VI	Input voltage	0		Vcc	0		Vcc	V
VO	Output voltage	0		Vcc	0		Vcc	V
ЮН	High-level output current			-24			-24	mA
loL	Low-level output current			24			24	mA
Δt/Δν	Input transition rise or fall rate	0		10	0		10	ns/V
TA	Operating free-air temperature	-55		125	-55		85	°C

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# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	Ι,,	T <sub>A</sub> = 25°C			54ACT11520		74ACT11520		UNIT	
		VCC	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII	
VOH	I <sub>OH</sub> = - 50 μA	4.5 V	4.4			4.4		4.4		V	
		5.5 V	5.4			5.4		5.4			
	I <sub>OH</sub> = - 24 mA	4.5 V	3.94			3.7		3.8			
	10H = -24 IIIA	5.5 V	4.94			4.7		4.8		v	
	$I_{OH} = -50 \text{ mA}^{\dagger}$	5.5 V				3.85					
	$I_{OH} = -75 \text{ mA}^{\dagger}$	5.5 V						3.85			
	10 504	4.5 V			0.1		0.1		0.1	V	
	I <sub>OL</sub> = 50 μA	5.5 V			0.1		0.1		0.1		
VoL	I <sub>OL</sub> = 24 mA	4.5 V			0.36		0.5		0.44		
		5.5 V			0.36		0.5		0.44		
	$I_{OL} = 50 \text{ mA}^{\dagger}$	5.5 V					1.65				
	I <sub>OL</sub> = 75 mA <sup>†</sup>	5.5 V							1.65		
lН	$V_I = V_{CC}$ , Q inputs only	5.5 V			10		10		10	μΑ	
I <sub>Ι</sub> Γ	$V_I = GND$ , Q inputs only	5.5 V		- 0.3	- 0.6		<b>–</b> 1		<b>–</b> 1	μΑ	
lį	$V_I = V_{CC}$ or GND, P and $\overline{G}$ inputs only	5.5 V			± 0.1		± 1		± 1	μΑ	
ICC	Q inputs at GND, Other inputs V <sub>I</sub> = V <sub>CC</sub> or GND	5.5 V		2.3	4.8		8		8	μΑ	
	Q inputs at open, Other inputs V <sub>I</sub> = V <sub>CC</sub> or GND	5.5 V			8		160		80	μΑ	
∆I <sub>CC</sub> ‡	Q inputs open, One input at 3.4 V and other inputs at V <sub>CC</sub> or GND, P and $\overline{G}$ inputs only	5.5 V			0.9		1		1	mA	
Ci	V <sub>I</sub> = V <sub>CC</sub> or GND	5 V		3.5						pF	

<sup>†</sup> Not more than one output should be tested at a time, and the duration of the test should not exceed 10 ms.

# switching characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

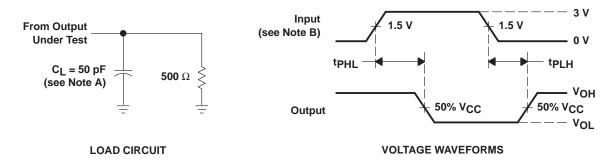
PARAMETER	FROM	то	T <sub>A</sub> = 25°C		54ACT	11520	74ACT11520		UNIT	
	(INPUT)	(OUTPUT)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	CIVIT
tPLH	P or Q	<u>P</u> = Q	1.5	8.6	12.7	1.5	15.4	1.5	14.3	ns
t <sub>PHL</sub>	Police		1.5	8	12.4	1.5	14.8	1.5	13.9	115
t <sub>PLH</sub>	G	P = Q	1.5	6.4	8.5	1.5	10.2	1.5	9.5	ns
<sup>t</sup> PHL	G		1.5	5.8	9	1.5	10.4	1.5	9.8	115

## operating characteristics, $V_{CC} = 5 \text{ V}$ , $T_A = 25^{\circ}\text{C}$

PARAMETER	TEST CONDITIONS	TYP	UNIT
C <sub>pd</sub> Power dissipation capacitance	$C_L = 50 \text{ pF}, \qquad f = 1 \text{ MHz}$	40	pF

<sup>‡</sup> This is the increase in supply current for each input that is at one of the specified TTL voltage levels rather than 0 V or VCC.

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. C<sub>L</sub> includes probe and jig capacitance.

- B. Input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \ \Omega$ ,  $t_f = 3 \ ns$ ,  $t_f = 3 \ ns$ .
- C. The outputs are measured one at a time with one input transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

#### **TYPICAL CHARACTERISTICS**

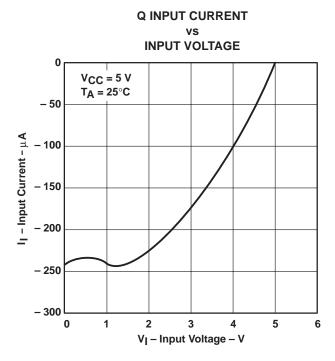


Figure 2

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